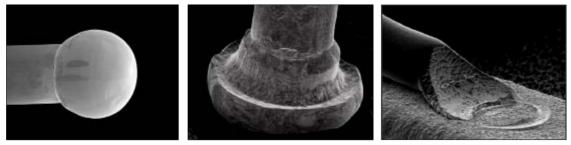
X-Wire[™] – Insulated Wire Bonding Technology

Advanced wire bonding technology is constantly being driven to higher geometric capability (finer pitches, longer loops) resulting in increasing packaging and assembly costs. X-Wire[™] Technology helps address these critical issues by providing a continuous insulating coating on today's bonding wires. X-Wire[™] Technology uses existing wire bond assembly infrastructure and processes.

Table 1, presents a typical X- Wire[™] bonding performance obtained on several package types representative of the present mix in semiconductor assembly operations. The evaluation was performed using an ASM® Eagle® 60 wire bonder, using capillaries from SPT.

Table 1: ASM[®] Evaluation of X-Wire[™]

	X-Wire™ Ø 20 μm	X-Wire [™] Ø 25 μm	
1 st Bond Geometry			
Bond Pad Pitch	50	65	
Ball Diameter (µm)	39	53	
Ball Height (µm)	10	12	
1 st Bond Strengths			
Shear Force (g)	12.0	23.2	
Shear Strength (g/mil ²)	6.5	6.9	
2 nd Bond Strengths			
Stitch Pull (g)	4.4	8.5	
Capillary	SPT SBN-25063-305F-ZP38T	SPT SBNE-33AR-AZM-1/16-XL	



Free Air Ball

1st Ball Bond

2nd Stitch Bond

The performance of X-Wire[™] Technology in trial production operations demonstrates the robustness required for present and future manufacturing requirements. First and second bond X-Wire[™] bond morphologies are shown in above, and are very typical of acceptable industry standards.

Microbonds





X-WireTM



Adhesion of the coating has been found to be exceptional before, during and after bonding operations. No de-lamination of the coating from the base wire is noted in the micrographs, notwithstanding the typical plastic deformation necessary to produce the second bond (stitch). During ball formation, the wire remains coated down to the neck and on top of the free air ball. During 2nd bond the coating exfoliates, by design, underneath the second bond, enabling a strong stitch bond, confirmed by pull strength. Special techniques developed by ASM® on the Eagle® 60 platform, can provide even higher pull strengths, when required.

20 µm X-Wire[™] – ASM Customer Evaluation

An ASM® customer identified a need for ultra-fine pitch insulated wire bonding to improve yield losses due to wire sweep. Through innovative ASM® bond process techniques, the previously recommended minimum bond pad pitch of 55 μ m was reduced to 47 μ m, with a 44 μ m bond pad opening. Using an SPT capillary, the bondability of 20 μ m X-WireTM met the customer qualification requirements in regards to strengths, geometry, IMC, and consistency. Results are shared in the Table 2 and images below.

1 st Bond Geometry		Standard Deviation	
Ball Diameter (µm)	35.5	0.4	
Ball Height (µm)	9.9	0.7	
1 st Bond Strengths			
Shear Force (g)	10.7	0.4	
Shear Strength (g/mil ²)	6.9	-	
2 nd Bond Strengths			
Stitch Pull (g)	4.4	0.3	
Neck Pull (g)	7.0	0.3	

Table 2: ASM[®] Evaluation 20 um Ø X-Wire^{™,} SPT Capillary



IMC

Stitch Bond





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Fine Pitch

